

TOSHIBA Field-Effect Transistor Silicon N Channel MOS Type

SSM3K36FS

○ High-Speed Switching Applications

1.5-V drive
 Low ON-resistance : Ron = 1.52 Ω (max) (@VGS = 1.5 V)

: Ron = 1.14 Ω (max) (@VGS = 1.8 V)

: $R_{on} = 0.85 \Omega \text{ (max) (@VGS = 2.5 V)}$

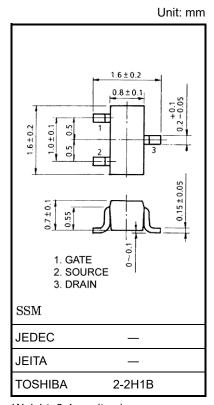
: Ron = 0.66Ω (max) (@VGS = 4.5 V)

: Ron = 0.63Ω (max) (@VGS = 5.0 V)

Absolute Maximum Ratings (Ta = 25 °C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DS}	20	V	
Gate-source voltage		Vgss	± 10	V	
Drain current	DC	ΙD	500	- mA	
	Pulse	IDP	1000		
Drain power dissipation		P _D (Note 1)	150	mW	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55 to 150	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.



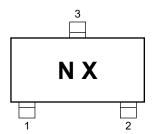
Weight: 2.4 mg (typ.)

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/ "Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

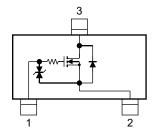
Note 1: Mounted on an FR4 board

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ mm}, \text{ Cu Pad: } 0.36 \text{ mm}^2 \times 3)$

Marking



Equivalent Circuit (top view)



Start of commercial production 2008-02

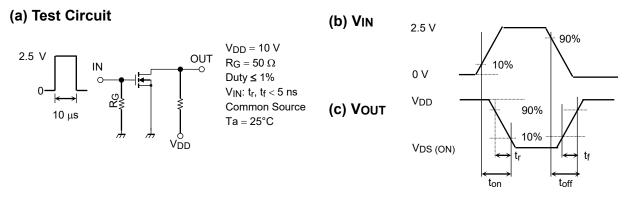


Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Conditions	Min	Тур.	Max	Unit
During a company has a balance and the	V (BR) DSS	$I_D = 1 \text{ mA}, V_{GS} = 0 \text{ V}$	20	_	_	V	
Drain-source breakdown voltage		V (BR) DSX	I _D = 1 mA, V _{GS} = - 10 V	12	_		_
Drain cutoff current		IDSS	V _{DS} = 20 V, V _{GS} = 0 V	_	_	1	μΑ
Gate leakage current		IGSS	$V_{GS} = \pm 10 \text{ V}, V_{DS} = 0 \text{ V}$	_	_	±1	μА
Gate threshold vol	tage	V _{th}	$V_{DS} = 3 \text{ V}, I_D = 1 \text{ mA}$	0.35	_	1.0	V
Forward transfer a	dmittance	Y _{fs}	$V_{DS} = 3 \text{ V}, I_D = 200 \text{ mA}$ (Note 2)	420	840	_	mS
Drain-source ON-resistance	Rds (ON)	I _D = 200 mA, V _G S = 5.0 V (Note 2)	_	0.46	0.63	Ω	
		I _D = 200 mA, V _G S = 4.5 V (Note 2)	_	0.51	0.66		
		I _D = 200 mA, V _{GS} = 2.5 V (Note 2)	_	0.66	0.85		
		I _D = 100 mA, V _{GS} = 1.8 V (Note 2)	_	0.81	1.14		
		I _D = 50 mA, V _G S = 1.5 V (Note 2)	_	0.95	1.52		
Input capacitance		Ciss		_	46	_	pF
Output capacitance		Coss	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	10.8	_	
Reverse transfer capacitance		C _{rss}		_	7.3	_	
Total Gate Charge Gate–Source Charge		Qg	V 40V I 05A	_	1.23	_	nC
		Q _{gs}	$V_{DS} = 10 \text{ V}, I_{D} = 0.5 \text{ A}$	_	0.60	_	
Gate–Drain Charge		Q _{gd}	V _{GS} = 4.0 V	_	0.63	_	
Switching time	Turn-on time	ton	V _{DD} = 10 V, I _D = 200 mA	_	30	_	ns
	Turn-off time	toff	$V_{GS} = 0$ to 2.5 V, $R_{G} = 50 \Omega$	_	75	_	
Drain-source forward voltage		VDSF	I _D = -0.5 A, V _G S = 0 V (Note 2)	_	-0.88	-1.2	٧

Note 2: Pulse test

Switching Time Test Circuit



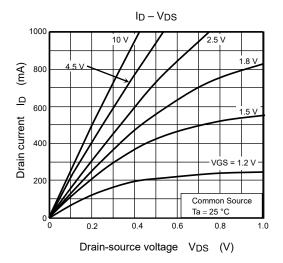
Usage Considerations

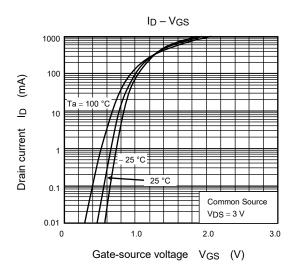
Let Vth be the voltage applied between gate and source that causes the drain current (ID) to below (1 mA for the SSM3K36FS). Then, for normal switching operation, VGS(on) must be higher than Vth, and VGS(off) must be lower than Vth. This relationship can be expressed as: VGS(off) < Vth < VGS(on). Take this into consideration when using the device.

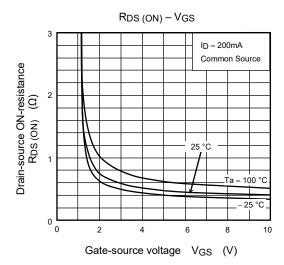
Handling Precaution

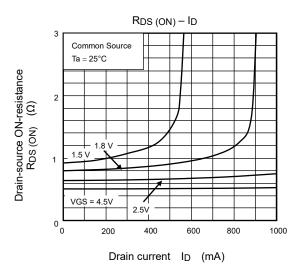
When handling individual devices that are not yet mounted on a circuit board, make sure that the environment is protected against electrostatic discharge. Operators should wear antistatic clothing, and containers and other objects that come into direct contact with devices should be made of antistatic materials.

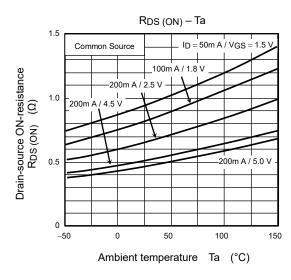


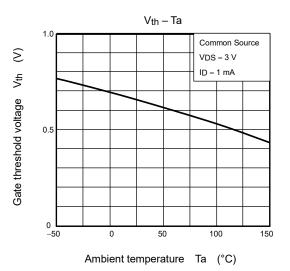




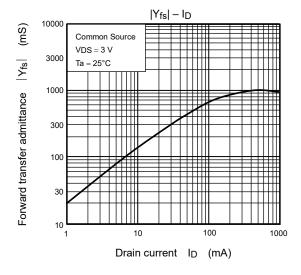


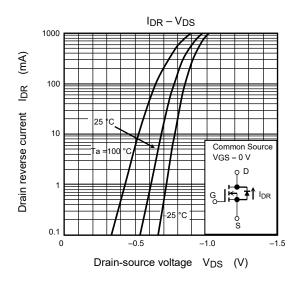


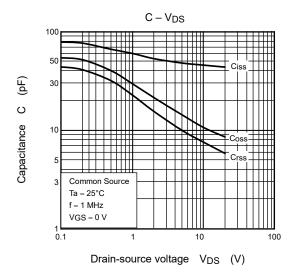


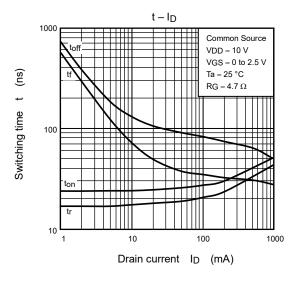


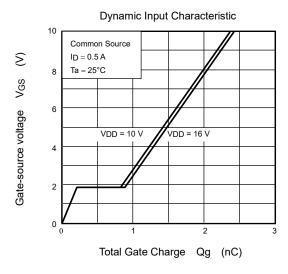
The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

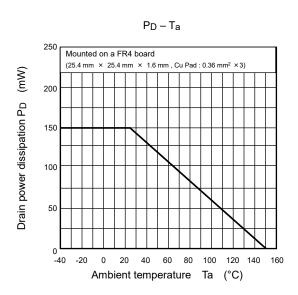












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